LOW-VOLTAGE 10-BIT BUS-EXCHANGE SWITCH

IDT74CBTLV3383

FEATURES:

- **5Ω A/B bi-directional bus switch**
- **Isolation under power-off conditions**
- **Over-voltage tolerant**
- **Latch-up performance exceeds 100mA**
- **Vcc = 2.3V - 3.6V, Normal Range**
- **ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)**
- **Available in SSOP, QSOP and TSSOP packages**

APPLICATIONS:

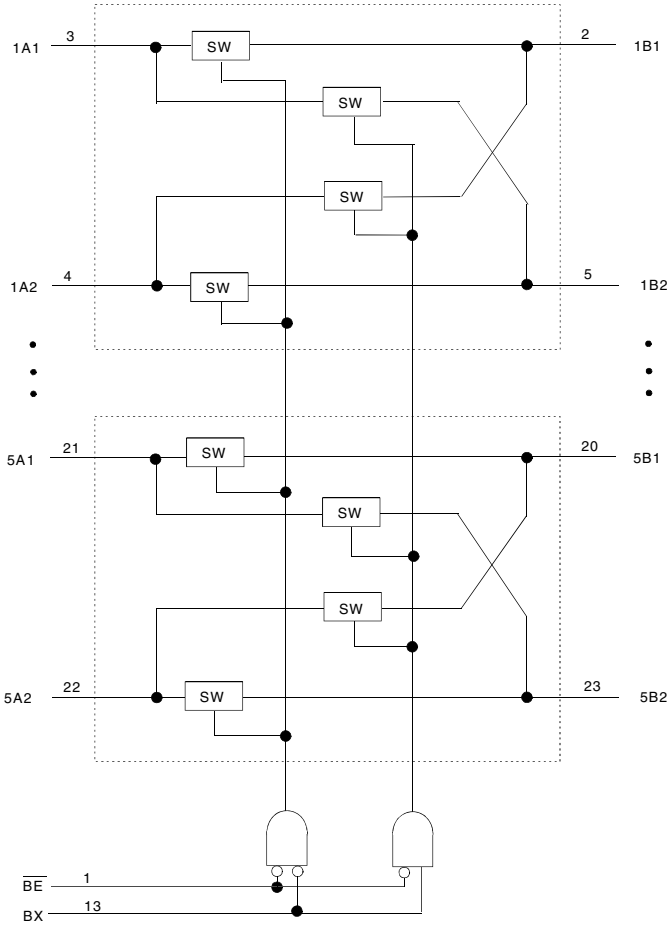
- **3.3V High Speed Bus Switching and Bus Isolation**
- **Crossbar Switching**

DESCRIPTION:

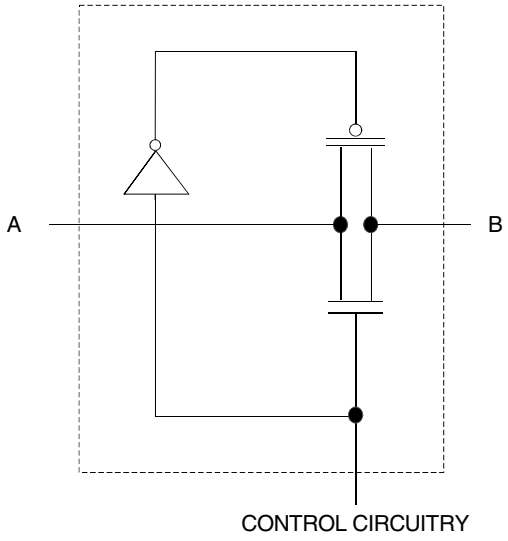
The CBTLV3383 provides ten bits of high-speed bus switching or exchanging with low on-switch resistance of the switch allowing connections to be made with minimal propagation delay.

The device operates as a 10-bit bus switch or a 5-bit bus exchanger, which provides swapping of the A and B pairs of signals. The bus-exchange function is selected when BX is high and $\overline{BE}$ is low.

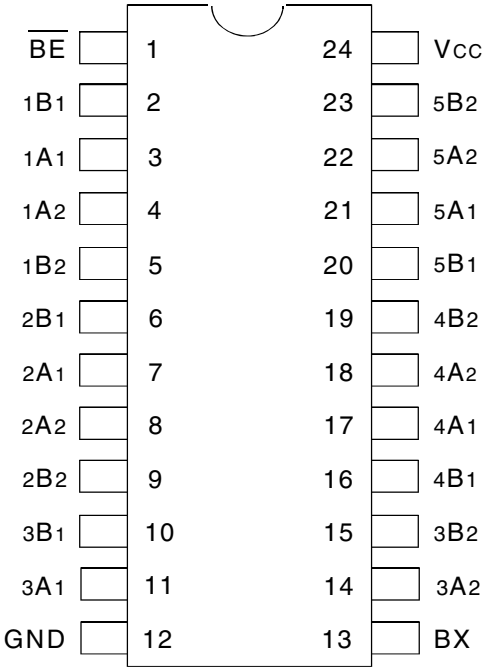
FUNCTIONAL BLOCK DIAGRAM



SIMPLIFIED SCHEMATIC, EACH SWITCH



PIN CONFIGURATION



SSOP/ QSOP/ TSSOP
TOP VIEW

ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max	Unit
V_{CC}	Supply Voltage Range	–0.5 to +4.6	V
V_I	Input Voltage Range	–0.5 to +4.6	V
	Continuous Channel Current	128	mA
I_{IK}	Input Clamp Current, $V_{I/O} < 0$	–50	mA
T_{STG}	Storage Temperature	–65 to +150	°C

NOTE:
1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

FUNCTION TABLE(1)

Input		Inputs/Outputs	
$\overline{BE}$	BX	1A1 - 5A1	1A2 - 5A2
L	L	1B1 - 5B1	1B2 - 5B2
L	H	1B2 - 5B2	1B1 - 5B1
H	X	Z	Z

NOTE:
1. H = HIGH Voltage Level
   X = Don't Care
   L = LOW Voltage Level
   Z = High Impedance

OPERATING CHARACTERISTICS, T_A = 25°C(1)

Symbol	Parameter	Test Conditions	Min.	Max.	Unit
V_{CC}	Supply Voltage		2.3	3.6	V
V_{IH}	High-Level Control Input Voltage	V_{CC} = 2.3V to 2.7V	1.7	—	V
		V_{CC} = 2.7V to 3.6V	2	—	
V_{IL}	Low-Level Control Input Voltage	V_{CC} = 2.3V to 2.7V	—	0.7	V
		V_{CC} = 2.7V to 3.6V	—	0.8	
T_A	Operating Free-Air Temperature		–40	85	°C

NOTE:
1. All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:
Operating Conditions: T_A = –40°C to +85°C

Symbol	Parameter	Test Conditions		Min.	Typ.(1)	Max.	Unit
V_{IK}	Control Inputs, Data Inputs	V_{CC} = 3V, I_I = –18mA		—	—	–1.2	V
I_I	Control Inputs	V_{CC} = 3.6V, V_I = V_{CC} or GND		—	—	±1	µA
I_{OZ}	Data I/O	V_{CC} = 3.6V, V_O = 0 or 3.6V, switch disabled		—	—	5	µA
I_{OFF}		V_{CC} = 0, V_I or V_O = 0 to 3.6V		—	—	10	µA
I_{CC}		V_{CC} = 3.6V, I_O = 0, V_I = V_{CC} or GND		—	—	10	µA
ΔI_{CC}(2)	Control Inputs	V_{CC} = 3.6V, one input at 3V, other inputs at V_{CC} or GND		—	—	300	µA
C_I	Control Inputs	V_I = 3V or 0		—	3.5	—	pF
$C_{IO(OFF)}$		V_O = 3V or 0, $\overline{BE}$ = V_{CC}		—	13.5	—	pF
R_{ON}(3)	V_{CC} = 2.3V Typ. at V_{CC} = 2.5V	V_I = 0	I_O = 64mA	—	5	8	Ω
			I_O = 24mA	—	5	8	
		V_I = 1.7V	I_O = 15mA	—	27	40	
	V_{CC} = 3V	V_I = 0	I_O = 64mA	—	5	7	
			I_O = 24mA	—	5	7	
		V_I = 2.4V	I_O = 15mA	—	10	15	

NOTES:
1. Typical values are at V_{CC} = 3.3V, +25°C ambient.
2. The increase in supply current is attributable to each current that is at the specified voltage level rather than V_{CC} or GND.
3. This is measured by the voltage drop between the A and B terminals at the indicated current through the switch. On-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

SWITCHING CHARACTERISTICS

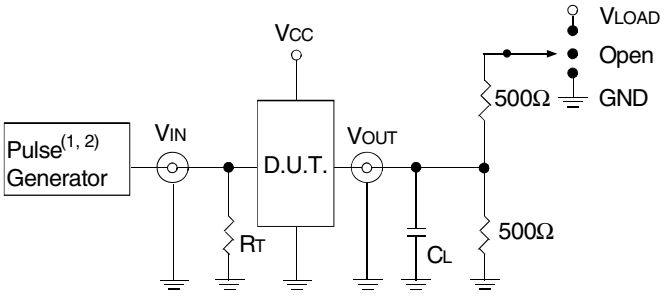
Symbol	Parameter	V_{CC} = 2.5V ± 0.2V			V_{CC} = 3.3V ± 0.3V			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	
t_{PD}(1)	Propagation Delay A to B or B to A	–	–	0.15	–	–	0.25	ns
t_{PD}	Propagation Delay BX to A or B	1.5	–	5.8	1.5	–	4.7	ns
t_{EN}	Output Enable Time $\overline{BE}$ to A or B	1.5	–	5.3	1.5	–	4.7	ns
t_{DIS}	Output Disable Time $\overline{BE}$ to A or B	1	–	6	1	–	6	ns

NOTE:
1. The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance driven by an ideal voltage source (zero output impedance).

TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

Symbol	$V_{CC}^{(1)}$ = 3.3V±0.3V	$V_{CC}^{(2)}$ = 2.5V±0.2V	Unit
V_{LOAD}	6	2 x Vcc	V
V_{IH}	3	Vcc	V
V_T	1.5	Vcc / 2	V
V_{LZ}	300	150	mV
V_{HZ}	300	150	mV
C_L	50	30	pF



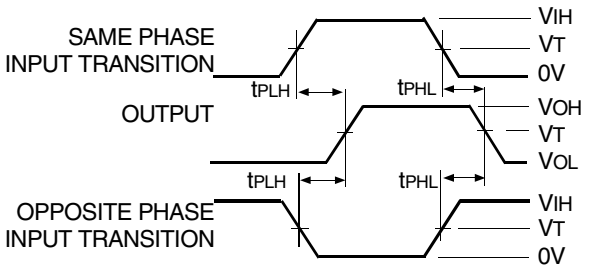
Test Circuits for All Outputs

DEFINITIONS:
C_L = Load capacitance: includes jig and probe capacitance.
R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

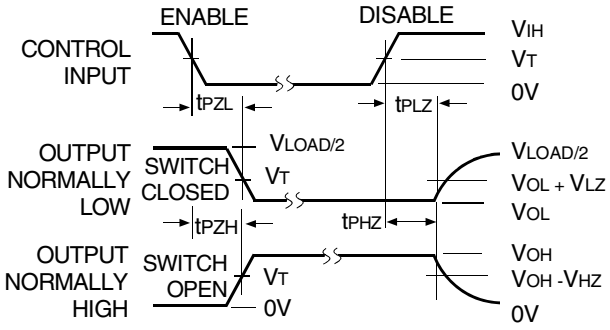
NOTES:
1. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_F ≤ 2.5ns; t_R ≤ 2.5ns.
2. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_F ≤ 2ns; t_R ≤ 2.5ns.

SWITCH POSITION

Test	Switch
t_{PLZ}/t_{PZL}	V_{LOAD}
t_{PHZ}/t_{PZH}	GND
t_{PD}	Open

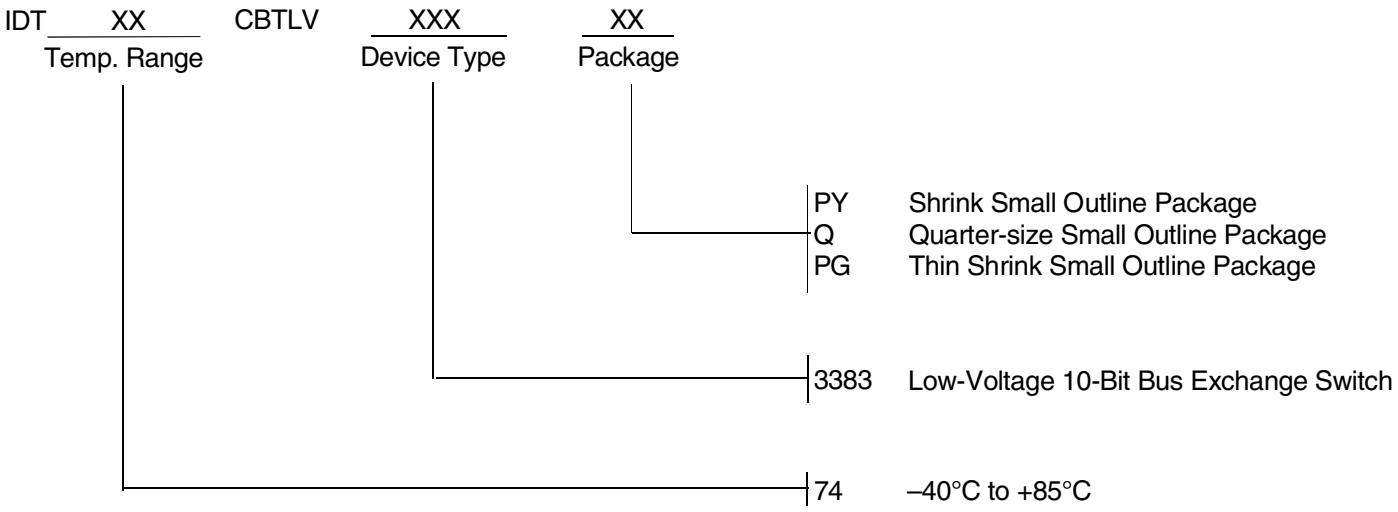


Propagation Delay



Enable and Disable Times

ORDERING INFORMATION



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